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FIRST PRINCIPLES MODELLING AND CHARACTERIZATION OF RADIATION POINT DEFECTS IN α -Al₂O₃ AND MgAl₂O₄ CRYSTALS

SUMMARY OF DOCTORAL THESIS

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Abstract

Corundum $(\alpha - Al_2O_3)$ and Mg-Al spinel (MgAl₂O₄) have high radiation stability, which makes them promising materials for high-energy nuclear technologies and future fusion reactors as a protective coating to avoid the light gases permeation, as well as corrosion produced by lithium-based alloys.

Despite the wide application and importance of these materials, the structure of the corresponding point defects is still not well studied from a theoretical point of view. Radiation-induced changes in the structural and optical properties of corundum are mainly associated with oxygen vacancies and complementary Frenkel pair defects (vacancy + interstitial oxygen atom). While oxygen vacancies are well-studied and easily identified, the complementary defect – the interstitial oxygen atom – has not been described in detail both experimentally and theoretically until now. The situation is similar for spinel crystals, as well another range of defects appears there - antisite defects, which also play an important role in the radiation resistance of the material.

Using quantum mechanical modelling code CRYSTAL17, which is based on the Density Functional Theory (DFT) and Linear Combination of Atomic Orbitals (LCAO), radiation defects in α -Al₂O₃ structure were investigated: both F-centers and interstitial oxygen defects in different charge states. The charge distribution in the Al and O sublattices, the defect geometry, as well as the recombination energy barrier, which characterizes the stability of primary defects, were analyzed. The application of Raman spectroscopy for defect identification was also proposed. The recombination energy barrier of the oxygen defect in MgAl₂O₄ was determined, as well as the EPR parameters of various antisite and vacancy defect (V-centers) of individual cations were calculated.

An efficient comparison of the calculated and experimental results allowed a deeper understanding of the behavior of Al₂O₃ and MgAl₂O₄ point defects, which can also be applied to the entire range of oxide materials.

List of abbrevations

OD zero-dimensional
 1D one-dimensional
 2D two-dimensional
 3D three-dimensional

ADP anisotropic displacements parameter

DFT density functional theory

dpa displasment per atom

DRC distinguished reaction coordinate
EPR electronic paramagnetic resonanse

HFS hyperfine structure

LCAO linear combination of atomic orbitals,

SHI switft heavy ion

TDE threshold displacement energy

VUV vacuum ultraviolet

XC exchange-corelation functional

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1. Introduction

1.1. Motivation

Wide-bandgap oxides such as MgO, α -Al₂O₃ (corundum), MgAl₂O₄ (spinel) are considered promising materials for diagnostic and optical components in nuclear fusion devices. The accumulation of radiation-induced defects affects the optical and other properties of the components. Thus, understanding the defect stability and recombination mechanisms becomes a very important issue.

It is generally accepted that the radiation resistance of functional materials is mainly determined by the accumulation of primary structural defects — vacancies + interstitial atoms, or Frenkel pairs. In the more complex structure of spinel, another stabilizing mechanism appears - antisite defects.

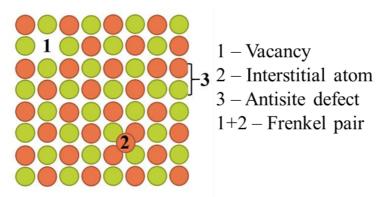


Figure 1.1. Crystal point defects, which were discussed in the thesis

All such defects were mostly studied with optical methods - they are widely available and allow for obtaining almost all the necessary information about the formation and evolution of the defects. However, for a long time, only vacancy defects were observed in experiments, with the interstitial atoms remaining invisible. Later, oxygen interstitial defects were detected in MgO, CaO, SrO and ZnO by EPR method.

Therefore, the main goals of this thesis are to understand the properties of oxygen defects in α -Al₂O₃ and MgAl₂O₄ crystals, to look at the properties of antisite defects, as well as to propose their possible

non-optical detection methods. To achieve these goals, the following tasks were set:

- Modeling of pristine crystals to select optimal calculation parameters that well describe the mechanical and electronic properties of crystals.
- Calculations of interstitial oxygen defects in different charge states (+1, 0, -1), analysis of their properties.
- Modeling of migration of interstitial oxygen defect in Al_2O_3 and $MgAl_2O_4$ crystals.
 - Modeling of antisite defects in MgAl₂O₄ crystals.
- Calculations of vacancy defects (or F-centers) and their dimers, determining their vibrational properties and simulating Raman spectra.

The work was performed within the framework of the EUROFUSION project (Enabling research and WP-MAT sub-projects), where scientists from other countries also participated, who conducted experimental research on these materials.

1.2. Author's contribution

The results described in this thesis have been summarized in eight high-ranking international publications [P1-P8] and were also presented at several local and international conferences with poster and oral presentations. The author has performed all calculations and their processing, was the responsible author for three publications, and played a significant role in writing all publications, as well as preparing conference abstracts and presentations. Two more methodological articles on point defects modeling are not included in this thesis [A1, A2]. Since 2016, the author has been acquiring computational resources at HELIOS (Japan) and CINECA-MARCONI (Italy) supercomputers, writing applications and reports on the use of resources. During the development of the work, the author has attended three international summer schools.

[P1] **Platonenko, A.**, Piskunov, S., Zhukovskii, Y.F., Kotomin, E.A., *Ab initio* simulations on Frenkel pairs of radiation defects in corundum, IOP Conference Series: Materials Science and Engineering, **77** (1) (2015): 012001. IF=0.53 (50% of the planning and writing; all calculations presented in the paper, corresponding author responsibility)

- [P2] Zhukovskii, Y.F., **Platonenko, A.,** Piskunov, S., Kotomin, E.A., *Ab initio* simulations on migration paths of interstitial oxygen in corundum, Nuclear Instruments and Methods in Physics Research, Section B: Beam Interactions with Materials and Atoms, **374** (2016): 29-34. IF=1.27 (70% of the planning and writing; all calculations presented in the paper)
- [P3] **Platonenko**, **A.**, Gryaznov, D., Piskunov, S., Zhukovskii, Y.F., Kotomin, E.A., Charged oxygen interstitials in corundum: first principles simulations, Physica Status Solidi (C) Current Topics in Solid State Physics, **13** (10-12) (2016): 932-936. IF=0.81 (75% of the planning and writing; all calculations presented in the paper, corresponding author responsibility)
- [P4] **Platonenko**, **A.**, Gryaznov, D., Zhukovskii, Y.F., Kotomin, E.A., *Ab initio* simulations on charged interstitial oxygen migration in corundum, Nuclear Instruments and Methods in Physics Research, Section B: Beam Interactions with Materials and Atoms, **435** (2018): 74-78. IF=1.27 (75% of the planning and writing; all calculations presented in the paper, submission preparation)
- [P5] **Platonenko, A.,** Gryaznov, D., Zhukovskii, Y.F., Kotomin, E.A., First Principles Simulations on Migration Paths of Oxygen Interstitials in MgAl₂O₄, Physica Status Solidi (B) Basic Research, **256** (5) (2019): 1800282. IF=1.48 (75% of the planning and writing; all calculations presented in the paper, submission preparation)
- [P6] **Platonenko**, **A.**, Gryaznov, D., Kotomin, E.A., Lushchik, A., Seeman, V., Popov, A.I., Hybrid density functional calculations of hyperfine coupling tensor for hole-type defects in MgAl₂O₄, Nuclear Instruments and Methods in Physics Research, Section B: Beam Interactions with Materials and Atoms, **464** (2020): 60-64. IF=1.27 (50% of the planning and writing; most calculations presented in the paper)
- [P7] Seeman, V., Lushchik, A., Shablonin, E., Prieditis, G., Gryaznov, D., **Platonenko, A.,** Kotomin, E. A., Popov, A. I., Atomic, electronic and magnetic structure of an oxygen interstitial in neutron-irradiated Al2O3 single crystals, Scientific Reports, **10** (2020): 15852. IF=4.58 (50% of the planning and writing of theoretical part of the paper; all *ab initio* calculations presented in the paper)
- [P8] **Platonenko**, **A.**, Gryaznov, D. Popov, A. I., Dovesi, R., Kotomin, E. A., First principles calculations of the vibrational properties of single and dimer F-type centers in corundum crystals, Journal of Chemical Physics, **153** (2020): 134107. IF=2.99 (80% of the planning and writing; all calculations presented in the paper, corresponding author responsibility)

1.3. Scientific novelty

The author's articles described for the first time the properties of oxygen interstitial defects and their migration in the crystal lattice, using large-scale models for calculations and applying advanced hybrid density functionals. It is shown that the oxygen interstitial defect can exist in different forms in both Al_2O_3 and $MgAl_2O_4$. These results were used to describe experimental observations in Al_2O_3 crystals.

Calculations of antisite defects (V-centers) in MgAl2O4 helped verify experimental observations.

For the first time, defect-induced vibrational modes have been calculated and demonstrated, which could be used to detect defects under conditions where optical measurements are not possible.

2. Literature review

2.1. Radiation-induced changes in crystalline materials

Particles with energy well above normal thermal energy ($E_{kin} > 1$ eV) exist in nature as cosmic rays or as a product of radioactive decay, but nowadays they are also artificially produced for scientific [1,2] and practical purposes [3,4].

The interaction of materials with high-energy particles results in the formation of defects when the kinetic energy of the particles is transferred to the atoms. In parallel with this, various electronic processes (excitation, generation of excitons and plasmons) and heating of the material can take place. The simplest defect that can form in all materials is a vacancy (V) and an interstitial atom (I), which are also called a Frenkel pair: when an atom is knocked out of its regular position, leaving behind a vacancy, but itself occupies a place in the lattice between other atoms [5]. Namely, more complex defects can also form: voids, amorphous regions, dislocations, defect clusters. The range of possible defects also depends on the type of compound: while only one type of V+I pair is possible in metals, oxides, where there are two types of atoms, will have both anionic and cationic defects. As well, in wide-band materials, electron localization in anion vacancies is possible [6].

Damage to the material under the influence of high-energy particles occurs in two stages: as a result of a primary particle-atom collision, when the kinetic energy of the particle dissipates in a cascade of collisions, due to which the material heats up strongly and the system is far from thermodynamic equilibrium. The second stage is the thermalization process, when the system comes to equilibrium, the duration of the first stage depends on the particle energy and temperature (shorter at higher temperatures), but is usually < 1 ps, but thermalization lasts up to 10 ps [5, 7].

Threshold displacement energy (TDE) is an important parameter for characterizing radiation damage. It is the amount of energy that is needed to knock an atom out of its equilibrium state and create a stable defect [8]. The possibility of defect formation below this energy is zero, but increases rapidly above it. Assuming that only one atom moves as a result of the collision and determining the potential energy barrier along a straight line in the direction of the initial recoil, it becomes clear that

the threshold displacement energy will depend on the orientation of the crystal. But this is a very simplified view of what happens after a high-energy particle collides with a crystal atom. In a crystal, each crystallographic direction corresponds to a separate displacement threshold energy [8].

The displacement threshold energy is determined both experimentally and with the help of simulations [9, 10]. Simulations were usually based on pair-potential molecular dynamics, but recently *ab initio* molecular dynamics is becoming increasingly popular.

Knowing how many and which stable defects will form as a result of irradiation, the radiation resistance of the material can be roughly estimated. The radiation resistance of metals has been studied since the middle of the last century, mainly trying to find out the effect of neutrons on the structural parts of nuclear reactors. Metals are very well described by classical molecular dynamics and relatively simple mathematical models (e.g. the Norgett, Robinson and Torrens (NRT) equation [11]), and experimental defect detection with *in situ* resistance measurements at low temperatures is very accurate and common [12]. Consequently, the level of understanding of radiation damage in metals is also the highest among all classes of materials [13].

Research on the radiation resistance of oxides has lagged behind that of metals for a long time, but is becoming increasingly relevant. The average value of TDE in oxides is between ~40 and ~100 eV, which is larger than in metals. In addition, only 20-50% of the defects predicted by NRT calculations in a wide radiation energy range are formed in oxides [14, 15]. Optical methods, electron magnetic resonance dominate among the available defect detection methods, but they are applicable only to a part of all defects, while defect clusters that do not have an optical or EPR signal remain invisible. One method that could help is, for example, small angle neutron scattering [16], but it is not so widely available.

Oxide materials are used in environments with high-energy radiation as functional materials (in components of diagnostic or optical devices) [17, 18], so it is important not only how their mechanical properties change, as might be the case for structural materials, but also to monitor the changes in optical, electronic and other properties. The efficiency of radiation damage in wide-bandgap (> 6 eV) metal oxides, which are characterized by a rather high Frenkel defect pair formation energy (significantly greater than the forbidden gap E_g), is highly dependent on the type of radiation. For example, ordinary X-rays and γ -

rays do not create new structural defects in metal oxides, but only charge already existing defects and impurities by induced charge transfer. Meanwhile, in other ionic materials – alkali metal halides – defects can form even under intense VUV radiation [19]. Using the ionization mechanism, a Frenkel pair is formed, the formation energy of which is lower than the band gap, as a result of the decay of an exciton of a non-radiative localized anion or as a result of the relaxation of an electron-hole pair [20]. When irradiating metal oxides with swift heavy ions (SHI), a large part of the energy is dissipated in the ionization processes that take place around the heavy ion in the crystal. It was shown that radiation damage is not significantly different in the results of neutron and SHI irradiation, so it was concluded that electronic excitation mechanisms only have a small effect on the formation of radiation defects [21, 22].

2.2. Radiation resistance of α-Al₂O₃

 $\alpha\text{-}Al_2O_3$ (corundum, sapphire) is a promising material for fusion reactors, e.g. for components such as breeding blankets and diagnostic windows [17, 23]. Thus, it is important to understand and control its radiation damage during intense neutron irradiation. It is known that as a result of exposure to radiation, pairs of Frenkel defects appear interstitial atoms and vacancies - in both cation and anion sublattices [24-26].

The crystal structure of α -Al₂O₃ belongs to the rhombohedral space group R-3c (No. 167) with a rhombohedral lattice containing two Al₂O₃ formula units (10 atoms) in each primitive cell [27]. The Al and O atoms occupy 4c (0 0 z) and 6e (x 0 ½) Wyckoff positions with site symmetry S3 = C3 and S2 = C2 and one free parameter in the hexagonal syngony, respectively. The crystallographic cell contains 6 formula units (30 atoms) (Fig. 2.1).

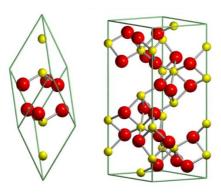


Figure 2.1. α -Al2O3 primitive 10-atom cell and crystallographic 30-atom unit cell.

Measured shifts in the threshold energy for corundum show that cations are more easily knocked out of the equilibrium position: 18-24 eV versus 70+ eV for anions [28, 29]. However, cationic sublattice defects do not accumulate in high concentrations [30], which is most likely due to very high defect mobility, and to observe them, irradiation and measurements at low temperatures should be performed. But since corundum is used at elevated temperatures in all radiation-related applications, cation defects do not significantly affect the properties of the material.

Anionic sublattice defects accumulated in alumina, affecting its optical and mechanical properties. The primary defect is an oxygen vacancy, where one (F^+ center) or two electrons (F center) can be localized. The F-center is characterized by a strong absorption band at 6 eV, while the F^+ center has two absorption bands: 5.3 eV and 4.8 eV [31, 32]. It should be noted that in all measurements the absorption of the F^+ center is much lower than the absorption of the F center. Under neutron irradiation, dimers of these defects are also formed - F_2 with different number of electrons.

It is assumed that the annealing of individual F-centers in neutron-irradiated metal oxides is due to the fact that interstitial oxygen atoms become mobile at elevated temperature and recombine with still immobile anion vacancies that are part of F^+ and F centers, while thermal annealing is due to the absorption of F and F^+ of bands in doped corundum, which does not contain anionic interstitial atoms, occurs at a significantly higher temperature [33].

In contrast to electron centers, the properties of interstitial oxygen atoms have been experimentally very little studied, as they do not have pronounced magnetic properties and optical absorption in a suitable energy range. Such studies are of great importance because in most binary oxides (as well as alkali halides), oxygen/halide interstitial atoms are more mobile than complementary vacancies, and their diffusion-controlled recombination determines stable defect concentrations at moderate and high temperatures [34]

Until these, some theoretical studies from the first principles were carried out on oxygen interstitial defects in different charge states in binary metal oxides [35, 36]. Interstitial atoms have been shown to bond with the lattice regular oxygen ion MgO [37, 38] and $\alpha\text{-Al}_2O_3$ [39, 40]. The description of the properties of interstitial defects in $\alpha\text{-Al}_2O_3$ is limited to the electronic structure, which contributes very little to the interpretation of experimental data.

Since the seventies of the last century, oxygen interstitial defects have been recorded by EPR in various oxides MgO [41], CaO [42], SrO [43] and others. At the time of writing this work, there was no such information about α -Al₂O₃, but now we can note the work [P8], where the oxygen interstitial defect in corundum was identified by the EPR method. As well as the work that was created in parallel with this within the framework of the project, where two absorption bands characteristic of interstitial defects were identified - 5.60 eV for a charged defect and 6.53 eV for a neutral defect. Analyzing the defect annealing process, the kinetic parameters of the process were also determined [44, 45].

2.3. Radiation resistance of MgAl₂O₄

Magnesium aluminum spinel MgAl₂O₄ represents a wide class of compounds with the general structural formula $A^{2+}B^{3+}{}_2O^{2-}{}_4$. The spinel structure belongs to the Fd3m space symmetry group (No. 227) [46]. Cations in it are located in voids in a tetrahedrally and octahedrally coordinated state in a cubic dense packing of oxygen. The unit cell contains 56 atoms (Fig. 2.2.): 32 oxygen atoms, which form 32 octahedral and 64 octahedral voids, of which eight tetrahedral positions are occupied by A^{2+} ions, and sixteen octahedral positions are occupied by B^{3+} ions.

The crystalline structure of spinel leaves a very large degree of freedom for the arrangement of ions in the lattice: spinel can be inverted, where A and B cations change places, the stoichiometry of the forming oxides can be in a wide range, maintaining the same structure.

But in this work, only non-inverted stoichiometric $1:1\ MgAl_2O_4$ compound was considered.

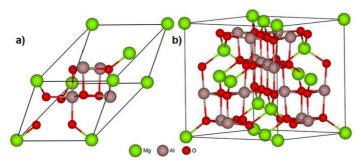


Figure 2.2. Primitive 14-atom cell (a) and crystallographic 56-atom unit cell (b)

MgAl₂O₄ has a very high resistance to neutron, ion and electron radiation up to extreme doses. At intense neutron irradiation [47], the spinel crystal does not change its size, while MgO and α-Al₂O₃ show volume changes >3% even at lower doses [48]. Such a property of spinel is explained by the effective recombination process of internode and vacancy defects, which takes place during irradiation. This possibility arises because, as mentioned above, there are already many vacancies in the spinel structure that participate in recombination processes. This, in turn, leads to the formation of antibonding defects. Such defects are charged relative to the ideal lattice (+1 or -1), so they charge-compensating defect nearby [49]. require a concentration of antibonding defects can reach several thousand ppm, but even then, strongly defined absorption bands associated with these defects do not appear [50].

As in all oxides, oxygen vacancies are also formed in spinel, where one or two electrons can be localized (F+ and F centers, respectively) [51]. The F-center has a pronounced absorption at 5.3 eV, the absorption intensity of the F+ centers is much lower and is at 4.8 eV. While the formation and evolution of F-centers was actively studied [52, 53], the complementary defect, the internodal oxygen atom Oi, received less attention. Calculations using pair potentials [54, 55] and an ab initio approach [A2] showed that, similar to corundum, Oi forms a molecular-type pair with the lattice oxygen ion. Meanwhile, their recombination process remains unclear.

Cation vacancies are always present in spinel crystals, regardless of the method of acquisition [56, 57]. They have an absorption band at 3.1 eV, with the help of which their concentration is usually determined. During irradiation, cation vacancies form more slowly than anion vacancies [58], to make them optically or EPR active, ionizing radiation is required to promote hole localization on a neighboring oxygen ion [59].

3. First principle calculations with CRYSTAL17 code

3.1. General information

Quantum mechanical modeling based on density functional theory (DFT) and periodic boundary conditions is one of the most popular methods for describing and predicting the properties of various materials. In recent decades, modeling from first principles has become a standard additional tool for characterizing materials and explaining experimental data [60]. High accuracy and relatively low demands on computing resources make it much more attractive than other methods.

CRYSTAL is one of many programs for DFT calculations. Unlike other available programs for modeling solids that use the plane wave approach, CRYSTAL relies on atom-centered Gaussian-type basis sets for atomic description (LCAO), which can use both all-electron basis sets and only valence electrons with an effective nuclear pseudopotential for a simplified description of the inner electron. This method historically comes from the field of quantum chemistry and modeling of molecules, but over time it has become suitable for modeling crystalline substances as well [61].

CRYSTAL can effectively model 3D periodic systems (crystals, amorphous substances), and structures with limited periodicity: surfaces and interfaces (2D), nanotubes, nanowires and polymers (1D), as well as non-periodic (0D) molecules and nanoparticles [61].

Effective parallelization of program algorithms allows the program to be used on powerful supercomputers, realizing their full potential. As the size of the system (the number of atoms) increases, the complexity of the calculations increases quadratically, so that hundreds or even thousands of processors are used to perform large calculations in a reasonable time. The developers of the program emphasize that, in

addition to high performance, it should also be ensured that the calculation accuracy remains at the same high level as the system size increases [62].

To start modeling a selected material, the user must first select two things: the basis set and the exchange-correlation (XC) functionals. The same chemical element can be in very different states (metal, ionic crystal, diamond and graphene) where the chemical bonds are very different. Different basis sets are developed to describe each case more precisely. A minimal atomic basis set will contain only filled electron orbitals – 1s in the case of a hydrogen atom, 1s2s2p – for an oxygen atom. To describe hybridization of orbitals and other processes related to the formation of chemical bonds, additional orbitals are added to the basis set. The larger the number of orbitals and associated functions, the more complicated the calculation will be. Basis sets for solid state calculations can be found on the website of the CRYSTAL developers [63]. There are also attempts to develop universal basis sets [64], as well as methods to optimize and adapt existing basis sets for a specific task [65]. It should be mentioned that despite the fact that there are a lot of basis sets for molecular calculations, most of them cannot be used for calculations of periodic systems.

Today, the number of exchange-correlation functionals is around a few hundred. Some are used very rarely and only for specific tasks, while others such as PBE [66] and B3LYP [67, 68] became the main choice for a wide variety of problems. Choosing XC functionally looks at how well it reproduces properties of interest, mainly forbidden zone width and lattice parameters. In recent decades, hybrid XCs have been preferred, where part of the exchange energy is replaced by the Hartree-Fock energy, which gives better results for the description of many properties. There is an opinion that the choice of functional is largely a personal choice and the evaluation of the effectiveness of different XCs depends on the chosen statistical indicators [61].

The user should always know which properties can be obtained from DFT calculations, which will require additional calculations but for which completely different methods need to be used. From a standard calculation (with geometry optimization) with the CRYSTAL program, without additional resources, we obtain:

- The total energy of the system;
- Equilibrium positions of atoms;
- Atomic force gradients;
- Band gap;

- Atomic charges;
- Hyperfine electron-nuclear spin interaction parameters (for spin polarized systems).

Using the calculated wave function, one can further calculate the band structure, density of states diagrams, charge distribution maps and others. It should be remembered that some interactions cannot be obtained from classical and hybrid DFT. For example, relativistic effects and related processes such as spin-orbit coupling cannot be calculated if they are not explicitly included in the chosen calculation method, another example is the evaluation of weak atom-atom dispersion forces, where an additional Grimme correction must be used [69].

3.2. Calculation methods of various properties

3.2.1. Defect modelling

To model isolated defects under periodic Born-Karman boundary conditions, the model size must be such that periodic spatially repeating defects do not interact with each other. The larger the defective supercell, the smaller their interaction, but the calculation time increases with the model size. Work [P2] showed that the properties of neutral interstitial oxygen defects in Al_2O_3 crystals do not differ in 120-atom and 270-atom cells, so a 120-atom supercell was used to model these defects in all works. Supercells up to 448 atoms were tested for MgAl₂O₄ calculations [P6]. A 270-atom supercell was used for vibrational property calculations in Al_2O_3 crystals of F and F₂ centers to achieve a relatively small concentration of F₂ defects..

The defect formation energy was calculated according to the equation:

 $E_f = E_D^q - E_0 - \sum_i n_i \mu_i + q(E_F + E_{VBM} + V) + E_{corr}^q$ (3.1) where E_D^q and E_0 are the total energy for a supercell with a defect in charge state q and the total energy for an ideal supercell, n_i is the number of atoms added or removed (n = -1 in the case of a vacancy), μ_i is the chemical potential of the element. E_F and E_{VBM} are the Fermi energy and valence band peak energy, V is the electrostatic potential equalization between supercells with and without defect. E_{corr}^q is the correction required in charged defect calculations to account for

interactions between periodically spaced point charges[70]. It should be mentioned that in order to perform calculations of the charged systems, the CRYSTAL17 program adds a compensating "background" charge so that the calculated system is not infinitely charged.

3.2.2. Calculations of the migration barrier

The migration barrier is the energy required for an atom to reach another position in the crystal lattice. Migration takes place in the direction of the complementary defect, so when two defects meet, they recombine. The calculations in this work are based on some assumptions:

- 1) Defects are located at a great distance and do not "feel" each other:
- 2) A moving defect is $O_{i,}$ because more energy is required to move the vacancy.

The "Distinguished Reaction Coordinate" (DRC) method was used to build a reaction coordinate diagrams and determine the migration barrier [71]. Finding the energy barrier with this method requires scanning calculations along the internal coordinate governing the reaction. In this case, the "reaction" can be described as the breaking of the O_i - O_{reg0} bond and the formation of a new O_i - O_{reg1} bond. This scan calculation changes the selected internal coordinate stepwise and in a controlled manner to move from the initial state to the final state, crossing the point of maximum energy. That the internal coordinate is used O_i - O_{reg1} distance, in this way every step it decreases, and O_i - O_{reg0} increases. The migration is considered complete when O_i reaches the same characteristics as at the starting point.

To test the method, a calculation was made for the interstitial oxygen defect in magnesium oxide. The cubic structure makes this material an ideal option for approbation of methods. The determined migration barrier is 1.4 eV (Fig. 3.1.), which agrees well with experimental observations [72].

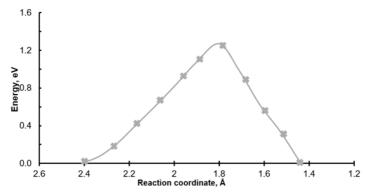


Figure 3.1. Reaction coordinate diagram for interstitial oxygen atom migration in MgO. The calculation was performed in a 64-atom supercell.

3.2.3. Vibrational properties

The vibrational frequencies at the gamma-point are obtained within the harmonic approximation [73, 74] by diagonalizing the massweighted Hessian matrix, the elements of which are defined as:

$$W_{\alpha i,\beta i}^{\Gamma} = \frac{H_{\alpha i,\beta i}^{0}}{\sqrt{M_{\alpha}M_{\beta}}}$$
 (3.2)

where M_{α} and M_{β} are the masses of the atoms associated with the coordinates of atoms i and j. The first derivatives of the energy with respect to atomic positions are calculated analytically for all coordinates, while the second derivatives are calculated numerically using one shift along each coordinate for each atom. The increase in energy at displacement calculations is ~10⁻⁵-10⁻⁷ Hartree, therefore these calculations should be performed with the qualitatively optimized geometry and increased accuracy. This is one of the more time consuming calculations as it requires N * 3 full energy calculations where N is the number of atoms in the cell (symmetric)

The thermal motions of atoms can be estimated from a calculated Hessian matrix, in work [P8] this parameter was used to show how far the effect of a defect manifests itself. Anisotropic displacement parameters (ADP) at a given temperature are calculated as 3×3 tensors UA associated with each atom in the A cell. Every 3×3 atomic tensor UA can be diagonalized as $U_AE_A=e_AE_A$, where e_A is the diagonal matrix of eigenvalues. If the three eigenvalues are positive, then the constant probability surfaces are ellipsoids, which include the probability of finding a given atom location. The lengths of the major

axes of the ellipsoids are proportional to the U_A eigenvalues e_1 , e_2 and e_3 , which are usually expressed as 10^{-4} A² [75].

3.3 Model and calculation parameters selection

In order to find a suitable calculation scheme, at the beginning of the work, calculations were performed with various functionals, using the smallest possible basis sets (Al – effective nuclear pseudopotential with valence $3s^23p^1$ electrons, O - 6s-2111sp-1d [63]), for the purpose of saving resources. The results of the calculations are listed in Table 3.1. Based on these results, the B3PW functional was chosen, which was used for most of the calculations. As available computing resources increased, the aluminum base set was replaced by the larger 8s-511sp-1d. For MgAl₂O₄ calculations, the same calculation parameters are used with the magnesium 8s-511sp basis set [63].

For the work on the vibrational properties of defects, it was separately tested how well the vibrational properties of an ideal crystal are reproduced (Table 3.2).

Table 3.1. Lattice parameters a and c, band gap and elastic constant for perfect corundum calculated using different exchange-correlation functionals. [P1]

| Method | a, | $\Delta a,*$ | с, | $\Delta c,*$ | Band gap | $\Delta \mathcal{E}_g, *$ | Elastic | constant | s, GPa [1 | .9] |
|--------------|-----------|--------------|------------|--------------|----------------------|---------------------------|----------|----------|-----------|-------|
| (functional) | Å | % | Å | % | \mathcal{E}_g , eV | % | C_{11} | Δ,* % | C_{44} | Δ,* % |
| Experimental | 4.76 [16] | | 12.99 [16] | | 8.8 [17] | | 496.5 | | 146.2 | |
| B3PW | 4.775 | 0.32 | 12.979 | -0.02 | 8.39 | -4.7 | 494.2 | -0.5 | 146.4 | 0.2 |
| B3LYP | 4.792 | 0.67 | 13.036 | 0.41 | 8.55 | -2.8 | 488.4 | -1.6 | 139.5 | -4.5 |
| HSE-sol | 4.744 | -0.35 | 12.884 | -0.75 | 8.25 | -6.3 | 516.8 | 4.1 | 150.2 | 2.8 |
| PBE | 4.788 | 0.59 | 12.987 | 0.04 | 6.01 | -31 | 469.5 | -5.4 | 142.3 | -2.6 |

^{*}as compared to experimentally found values written in previous columns

Table 3.2. Calculated and experimental Raman and IR modes of perfect α -Al₂O₃. Mode symmetry is given in parenthesis. [P8]

| Rama | nn, cm-1 | IR, cm-1 | | |
|------------------------|--------------|------------------------|-----------|--|
| Calc. | Experimental | Calc. | Exp. | |
| This work | Ref. [76] | This work | Ref. [77] | |
| 378 (E _g) | 376 | 382 (E _u) | 385 | |
| 412 (A _{1g}) | 413 | 393 (A _{2u}) | 400 | |
| 421 (E _g) | 428 | 436 (E _u) | 442 | |
| 451 (E _g) | 440 | 560 (E _u) | 569 | |
| 576 (E _g) | 573 | 575 (A _{2u}) | 583 | |
| 643 (A _{1g}) | 642 | 635 (E _u) | 635 | |
| 752 (E _g) | 748 | | | |

4. Main results

4.1. Oxygen interstitial defects structure and properties

The first step in this work was to determine the structure of the neutral oxygen interstitial defect [P1, A1]. Later, other charge states were also explored: -1, 0, +1. It was concluded that in all cases the interstitial oxygen (O_i) occupies a position next to the regular oxygen atom (O_{reg}) (Fig. 4.1).

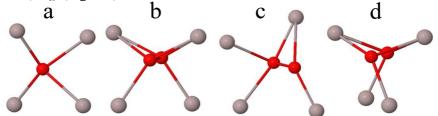


Figure 4.1. Oxygen site in α -Al₂O₃ lattice: a) without defect (O_{reg}), b) neutral interstitial oxygen defect, c) positively charged and d) negatively charged.

Table 4.1. Basic properties of the interstitial oxygen defect in different charge states in α -Al₂O₃ crystals.

| Defect | O _{reg} | $O_2^{2-}(q=0)$ | $O_2^-(q=+1)$ | $O_2^{"3-"}(q=-1)$ |
|---|------------------|-----------------|----------------------------|--------------------|
| Charge, e | -1.38 | -0.74 / -0.74 | -0.27 / -0.66 | -1.05 / -1.05 |
| d _{O-O} , Å | - | 1.44 | 1.33 | 1.87 |
| d _{O-Al} , Å | 1.86, 1.97 | 1.85, 1.92 | 1.76 / 1.89, 2.04, 2.05 | 1.84, 1.85 |
| Vibrational frequency, cm ⁻¹ | - | 1069 | 1183 | 963 |

Looking at the properties of all defects, it can be concluded that some of them have a lot in common with the oxygen peroxide $O_2^{2^-}$ and superoxide O_2^{-1} forms [78]. This can be inferred from both bond lengths and vibrational frequencies. A positively charged defect is also distinguished by the fact that in its case O_i and O_{reg} are not equal and symmetrical. The symmetric form was also modelled, but its energy was 0.2 eV higher. A negatively charged defect differs from the others with a longer bond length, which is not typical for widely known oxygen bond forms, but resembles the form of oxygen in the high-pressure FeO₂

bond, where the O_2^{3-} ion formally exists and the O-O bond is 1.937 Å [79].

The electron density distribution was analyzed using the electron localization function and the Laplacian of the electron density (Fig. 4.2). Electron localization function is a measure of probability of finding an electron in the neighborhood space of a reference electron located at a given point and with the same spin, and the Laplacian of the electron density represents the structure of the atomic shell, which changed its shape as a result of covalent bond formation and hybridization [80]. In the case of neutral and positively charged defects, the total electron density between the two atoms can be seen very well, indicating the formation of a bond. A negatively charged defect does not create shared electron density, so it cannot be said that a molecule-type structure is formed, but two separate atoms that arrange themselves in the crystal lattice.

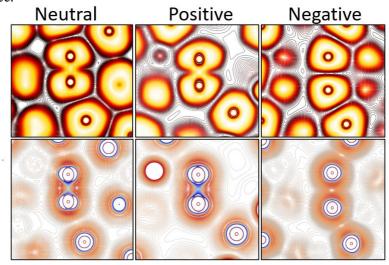


Figure 4.2. Interstitial oxygen defects in different charge states. 2D distribution of electron density using electron localization functions (top) and Laplacian of electron density (bottom).

The defect formation energy (Fig. 4.3) was calculated for all three charge states as a function of the Fermi energy, which is taken in the interval from the maximum of the valence band ($\varepsilon_{\text{Fermi}}$ =0) to the minimum of the conduction band. All three states are shown to have their own region of stability. O₂⁻ (q=+1) is more stable at lower Fermi energy, which is characteristic of hole-type defects. Two paramagnetic

defects are expected to have smaller stability regions than diamagnetic $O_2^{2^-}$ (q=0). This state was later also observed experimentally, where an absorption band at 6.53 eV was identified for this defect, while the defect in the q=+1 state forms an absorption band at 5.61 eV, and was also identified by the EPR technique [4, P8]. Meanwhile, the q=-1 state could play an important role in the defect recombination process, which will be discussed later.

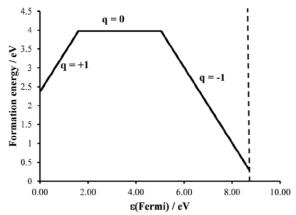


Figure 4.3. Formation energy of interstitial oxygen defects as a function of Fermi energy. Dashed line indicates the width of the band gap. [P8]

Only q=0 and q=-1 states were considered in MgAl₂O₄ crystals. The properties of the defects in the two compounds are very similar, both in terms of bond lengths and charge distribution. As an example, we can look at the density state diagrams for defects in both crystals (Fig. 4.4). Both α -Al₂O₃ and MgAl₂O₄ neutral (q=0) defects form occupied states immediately around the top of the valence band and unoccupied ones 8 eV higher. For negative defects, the diagram is slightly different, but in general their characteristics are also very similar.

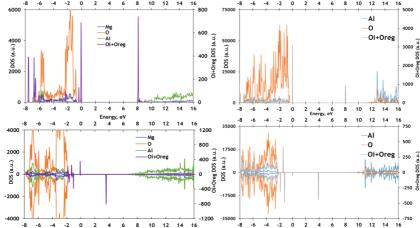


Figure 4.4. Density of states diagram of MgAl₂O₄ (left) and α -Al₂O₃ (right) with neutral (top) and negatively charged (bottom) oxygen interstitial defects. O_i+O_{reg} DOS shows the states introduced by oxygen defects, O – states of regular oxygen ions [P7]

4.2. Migration of oxygen interstitial defects in the crystal lattice

4.2.1. α -Al₂O₃

After determining the structure of the oxygen interstitial defect, the migration of this defect in the crystal lattice can be modelled. The defect was assumed to move through the lattice in a stepwise manner, with each step occupying a ground state.

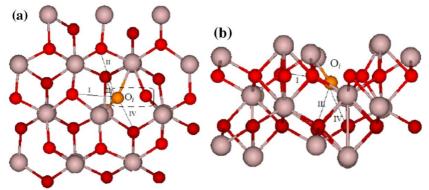


Figure 4.5. Four possible migration paths of the neutral interstitial oxygen

atom in the α -Al2O3 lattice, top (0001) (a) and edge (b) views. Trajectories show the direction of a migration. Paths I and II are "in-plane" and III and IV – inter-plane. [P2]

The directions towards the nearest oxygen atoms were chosen as trajectories (Fig. 4.5.). Trajectories I and II start and end on the same (0001) plane, while trajectories III and IV pass between the two nearest planes. The initial migration jump lengths change in the following order: $d_{\rm I} < d_{\rm III} < d_{\rm IV}$.

Three of the four energy curves, which were obtained using Distinguished Reaction Coordinate" (DRC), shown in Figure 4.6 cross a single barrier, while energy curve IV is characterized by a double-barrier profile, where the first barrier is associated with a 90-degree rotation of the Oi-Oreg structure, followed by single bond breaking and new bond formation. The calculated value of the migration barrier is ~1.3 eV, which is practically the same for three of the four trajectories. This value is very similar to that calculated for the case of MgO. But the calculated barrier is larger than it is observed in experiments – 0.2-0.9 eV, depending on irradiation conditions and dose [22]. Therefore, another model had to be considered.

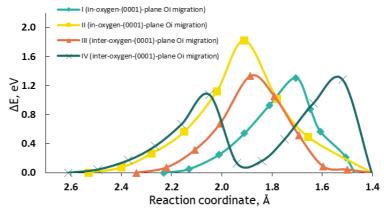


Figure 4.6. Reaction coordinate diagram for four interstitial oxygen atom migration paths in corundum I, II, III and IV (Fig. 4.5.) and calculated energy barriers [P2]

Taking into account the properties of the oxygen interstitial defect in different charge states and experimental observations, O_i q=-1 defect migration was modelled next. From the analysis of the electron density,

it could be concluded that in this state the O-O bond is the weakest, therefore the migration barrier should be lower.

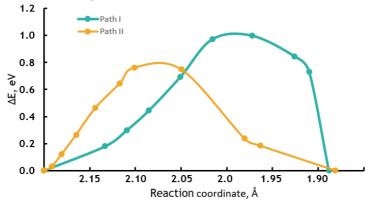


Figure 4.7. Reaction coordinate diagram for two negatively charged interstitial oxygen atom migration pathways and calculated energy barriers. [P6]

Four trajectories were considered in the work [P6]. But we managed to successfully model only two, which are shown in Figure 4.7. Difficulties in the calculations are mainly due to the fact that the extra electron during the migration cannot be localized so easily, and due to the larger initial O-O distance, the O_i atom in some trajectories is very close to other ions during the migration. The calculated barrier value is ~ 0.8 eV, which is in good agreement with experimental observations.

4.2.2. $MgAl_2O_4$

In the case of spinel, the migration of two types of defects was also examined. For a neutral defect, migration paths and calculated energy curves are shown in Figure 4.8. The three regular oxygen atoms closest to O_i (up to 2.5 Å away) were chosen as the final position for migration. The migration paths can be characterized as one-dimensional migration: path I lies in the <100> direction, paths II and III are oriented in the <110> direction. All pathways reveal a clear energy barrier and end in the formation of a new O-O pair with the regular oxygen atom

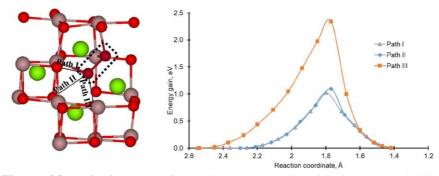


Figure 4.8. Left: fragment of a 113-atom supercell with three neutral Oi migration paths in a spinel crystal. Right: reaction coordinate diagram for three migration pathways and calculated energy barriers. [P7]

The calculated barriers are between 1.0 and 2.4 eV. A closer look at the peak point of trajectory III clearly shows that the increase in the energy barrier occurs due to the strong interaction with the Mg ion. At the same time, the O–O bond lengths and electronic structure are very similar for trajectories I and II. The only difference is the interaction with the Mg ion instead of the Al ion. This effect could be particularly important in Mg-rich spinels, where antisite defects in Mg_{Al} are common, which can affect oxygen migration.

Migration barriers are smaller than calculated for neutral oxygen interstitials in corundum (1.3 eV) and MgO (1.45 eV). If we assume that the limiting step for the migration of neutral oxygen interstitials is the breaking of the O–O bond, it can be concluded that an asymmetric environment in spinel could reduce the energy of this bond.

Unlike neutral O_i , the negatively charged O_i ion in spinel symmetrically occupies a regular oxygen site: each of two oxygen atoms forms covalent bonds with 2 Al atoms and one ionic bond with a Mg atom. There are two symmetric non-equivalent migration paths for the migration of interstitials between the nearest oxygen atoms (Fig. 4.9.).

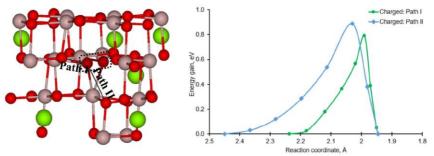


Figure 4.9. Left: fragment of a 113-atom supercell with two migration paths of negatively charged O_i in a spinel crystal. Right: energy curves for two migration pathways and calculated energy barriers. [P7]

Similar to the migration of a neutral O_i atom, trajectory I is oriented in the <100> direction and trajectory II along <110>. The calculated migration paths show lower energy barriers of 0.8–0.9 eV than for neutral Oi. Unfortunately, no experimental data on the recombination of oxygen defects in spinel crystals were found during the work.

4.3. MgAl₂O₄ antisite defects properties and EPR parameters calculations

A series of EPR active defects were calculated for spinel crystals, which were experimentally observed [49]: $V_1(=V_{Al}^{2-}+O^-)$, $V_2(=V_{Mg}^{1-}+O^-)$ and $V_{22}(=Mg_{Al}^0+O^-)$. Next to each defect is an O^- with a localized hole that produces an EPR signal. The spin density distribution is shown in Figure 4.10, where you can clearly see the localization of the hole and the oxygen ion, and a small spin density on neighboring oxygen ions.

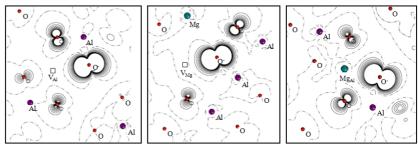


Figure 4.10. 2D spin density maps of V_{Al} , V_{Mg} and Mg_{Al} defects.

The calculated EPR parameters (Table 4.2) show nearly identical components of the Hyperfine Structure (HFS) tensor discussed [49], and are confirmed here for all three cases of V-centers despite the low symmetry. It should be noted that the centers of V_1 and V_{22} were calculated without symmetry constraints. While the relative calculation error may seem large, the absolute difference of 0.2 mT is small and within the accuracy of the calculation method.

Table 4.2. Calculated HFS parameters for V defects in spinel. Experimental values [49] are given in parentheses HFS parametres refers to aluminum ions adjacent to O⁻.

| Defect | A _{iso} / mT | A_x / mT | A_y / mT | A_z / mT |
|----------|-----------------------|------------|------------|------------|
| V_1 | -0.60 | -0.63 | -0.65 | -0.68 |
| | | (0.86) | (0.86) | (0.93) |
| V_2 | -0.71 | -0.72 | -0.71 | -0.60 |
| V_{22} | -0.58 | -0.62 | -0.60 | -0.63 |
| | | (0.45) | (0.45) | (0.46) |

We calculated the formation energies (Fig. 4.11.) for vacancies and antisite defects in different charge states. V_1 center corresponds to aluminum vacancy in -2 charge state formation, V_2 center is Mg vacancy in charge state -1, and neutral MgAI antisite defect is V_{22} center. As expected, cation vacancies have the lowest formation energies in the highest charge states. The overall picture shows that the formation energies of the two cations are close in the corresponding charge states. Only the appearance of the -3 charge state of the Al vacancy makes this vacancy more energetically favorable compared to the -2 charge state of the Mg vacancy. However, the formation of an antisite defect is always the most advantageous, but it does not exclude the formation of other defects.

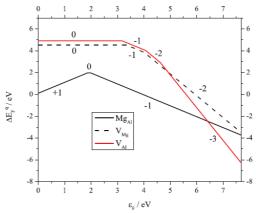


Figure 4.11. Formation energies of $V_{\text{Al}},\,V_{\text{Mg}}$ and Mg_{Al} defects as a function of Fermi energy.

4.4. Vibrational modes induced by point defects in α-Al₂O₃ crystals

In the last stage of the work, the vibrational properties of F-centers in α -Al₂O₃ crystals were examined. Compared to interstitial defects, the structure of F-centers is much simpler (Fig. 4.12), but the identification of induced vibration modes is more complicated. In total, two defects in three charge states were considered, all of them have been observed experimentally by optical methods [32].

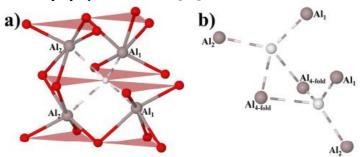


Figure 4.12. Schematic representation of F (a) and F_2 (b) centers in the α -Al₂O₃ structure. Al₁ and Al₂ are at different distances from the defect.

The results of the work [P8] on defect characteristics are summarized in table 4.3.

Table 4.3. Calculated distances from the vacancy site to the nearest Al atoms $(d_{V^-Alx}, \mathring{A})$, Al-O bond length intervals for Al atoms around the vacancy $(d_{Alx^-O}, \mathring{A})$, charge (q, |e|) and magnetic moment (μ, μ_B) , which is localized in the vacancy according to the results of the Mulliken analysis. Defect modes (cm^{-1}) were assigned by isotopic substitution analysis.

| Defect | d_{V-Alx} | d_{Alx-O} | q | μ | Defect modes |
|--------------------|------------------------|----------------------------------|------|------|---------------------------------|
| F | Al ₁ : 1.75 | Al ₁ : 1.88-2.10 | 1.46 | 0 | 146, 181, 231, |
| | Al ₂ : 2.01 | Al ₂ : 1.85-1.97 | | | 234, 252, 518 |
| \mathbf{F}^{+} | Al1: 1.98 | Al ₁ :1.85-1.96 | 0.87 | 0.66 | 214, 246, 248, |
| F | Al2: 2.10 | Al ₂ : 1.80-1.98 | 0.07 | 0.00 | 257, 830, 839 |
| F ²⁺ | Al1: 2.17 | Al ₁ :1.79-1.95 | 0.25 | 5 0 | 714, 721, 848, |
| T' | Al2: 2.17 | Al ₂ : 1.76-1.99 | 0.23 | U | 873, 891, 896 |
| | Al1: 1.75 | Al ₁ :1.88-2.09 | | | 179, 231, 233, |
| \mathbf{F}_2 | Al2: 1.81 | Al ₂ : 1.87-2.04 | 2.93 | 0 | 238, 251, 335, 482 |
| | | Al _{4-fold} : 1.86-1.97 | | | |
| | Al1: 1.90 | Al ₁ :1.85-1.96 | | | 104 241 242 |
| ${\bf F_2}^+$ | Al2: 1.97 | Al ₂ : 1.85-1.95 | 2.3 | 0.68 | 184, 241, 243, 253, 337, 543 |
| | | Al _{4-fold} : 1.84-1.97 | | | |
| | Al1: 2.01 | Al ₁ :1.84-1.96 | | | 102 104 242 |
| ${{\bf F_2}^{2+}}$ | Al2: 2.11 | Al ₂ :1.83-1.98 | 1.64 | 0 | 123, 184, 242, 250, 255, 835 |
| | | Al _{4-fold} : 1.78-1.91 | | | |

First, the relaxation of atoms around the defects was analyzed. Similar trends were observed for the relaxation of mono- and dimer defects. Isotope substitution analysis was used to identify defect modes among several other modes (the calculation was performed in a 270-atom supercell without symmetry operators). All aluminum atoms (27 Al) around the defects were replaced by heavier 29 Al. This causes the frequencies of all modes associated with these atoms to be shifted to lower values (equation 3.2). From all the results, the F^{2+} defect, whose induced modes are in the region of 700-900 cm-1, stands out. To explain this, the anisotropic displacement parameters (ADP) of atoms were examined (Fig. 4.13).

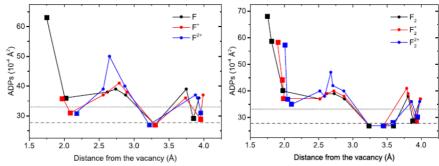


Figure 4.13. Anisotropic displacement parameters (ADP) for aluminum (squares) and oxygen (circles) atoms around defects. Horizontal dashed and dotted lines represent isotropic displacement parameters for aluminum and oxygen in an ideal crystal.

In ideal corundum, the ADPs of oxygen and aluminum are nearly isotropic, with little elongation along the z axis. The ellipsoids were found to be strongly anisotropic along the defect direction, here the maximum values of the three semi-axes of the thermal ellipsoids are visualized as a function of the distance of the oxygen and aluminum atoms from the vacancy. As expected, in the case of the F-center, the two Al atoms closest to the vacancy have an ADP almost three times larger than in the ideal crystal, while the other two Al atoms have a much smaller thermal ellipsoid, similar to the aluminum atoms at F⁺ and F²⁺ defects. The second interesting observation revealed by studying ADP is the thermal motion of oxygen atoms in the second coordination sphere (distance 2.4 Å) of the F^{2+} center defect: here they have much larger ellipsoids than in other defects. The ADP analysis is consistent with the above considerations regarding changes in Al-O bonds. Induced modes in the low-frequency region for the F-center are associated with a shorter Al-vacancy distance (and thus longer Al-O bonds). On the contrary, induced modes in the high-frequency region (700-900 cm⁻¹) for the F²⁺-center are associated with longer Al-vacancy distances and the involvement of oxygen atoms in thermal motion due to shorter Al-O bonds.

5. Summary

This thesis is a systematic study of point defects in oxide materials α -Al₂O₃ and MgAl₂O₄, where special attention is paid to oxygen defects and related processes. The chosen method – hybrid DFT with LCAO approach – was tested for several basic parameters, such as lattice parameters, elastic modulus, and vibrational frequencies. The calculation results are in good agreement with the experimental results obtained during the work within the EUROfusion projects. An efficient comparison of calculation and experimental results allowed a deeper understanding of the behavior of Al₂O₃ and MgAl₂O₄ point defects, which can also be applied to the entire range of oxide materials.

For the first time stable configurations of the interstitial oxygen defect in -1/0/+1 charge states in Al_2O_3 crystals were determined. From the results of the defect migration modeling, it is concluded that the defect migration occurs in the 0 or -1 state. While in the ground state, the defect is most likely to exist in the +1 and 0 states, as shown by the experimental data. From this it can be concluded that the activation of defects occurs by electron capture.

Very similar results were obtained for $MgAl_2O_4$ crystals. Unfortunately, good experimental data on oxygen migration in these crystals are not yet available. The calculated electronic properties, structure and EPR parameters of EPR active defects are in good agreement with experimental data.

Vacancy defects in Al_2O_3 crystals have their own characteristic vibrational modes that could be observed by vibrational spectroscopy methods. Especially when radiation-induced defects are present at high concentrations and optical methods are no longer useful due to absorption saturation.

All work results have been systematized and published. They were used to explain and confirm the experimental results. The methods used in the work can be applied in the research of radiation properties in other materials as well.

6. Main theses

The chosen approach for *ab initio* calculations of corundum and magnesium aluminate spinel was tested by a comparison of basic bulk properties with available experimental and theoretical data

- Oxygen interstitial defects in α -Al₂O₃ and MgAl₂O₄ are stable in neutral, positively charged or negatively charged state depending on experimental conditions. Interstitial defect migration occurs in a negatively charged form.
- V-centers associated with antisite defects or cation vacancies in MgAl₂O₄ crystals and localized holes on oxygen ions generate different EPR signals that can be distinguished and identified through *ab initio* calculation.
- All oxygen defects in α-Al₂O₃ crystals have their own characteristic and well-distinguishable vibrational modes, which could be observed by Raman spectroscopy methods. The vibration frequencies of the modes depend on the defect charge.

7. Literature

7.1. Author's publications related to this work

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- [P2] Zhukovskii, Y.F., **Platonenko, A.,** Piskunov, S., Kotomin, E.A., *Ab initio* simulations on migration paths of interstitial oxygen in corundum, Nuclear Instruments and Methods in Physics Research, Section B: Beam Interactions with Materials and Atoms, **374** (2016): 29-34. IF=1.27
- [P3] **Platonenko**, **A.**, Gryaznov, D., Piskunov, S., Zhukovskii, Y.F., Kotomin, E.A., Charged oxygen interstitials in corundum: first principles simulations, Physica Status Solidi (C) Current Topics in Solid State Physics, **13** (10-12) (2016): 932-936. IF=0.81
- [P4] **Platonenko, A.,** Gryaznov, D., Zhukovskii, Y.F., Kotomin, E.A., *Ab initio* simulations on charged interstitial oxygen migration in corundum, Nuclear Instruments and Methods in Physics Research, Section B: Beam Interactions with Materials and Atoms, **435** (2018): 74-78. IF=1.27
- [P5] **Platonenko, A.,** Gryaznov, D., Zhukovskii, Y.F., Kotomin, E.A., First Principles Simulations on Migration Paths of Oxygen Interstitials in MgAl₂O₄, Physica Status Solidi (B) Basic Research, **256** (5) (2019): 1800282. IF=1.48

- [P6] **Platonenko**, **A.**, Gryaznov, D., Kotomin, E.A., Lushchik, A., Seeman, V., Popov, A.I., Hybrid density functional calculations of hyperfine coupling tensor for hole-type defects in MgAl₂O₄, Nuclear Instruments and Methods in Physics Research, Section B: Beam Interactions with Materials and Atoms, **464** (2020): 60-64. IF=1.27
- [P7] Seeman, V., Lushchik, A., Shablonin, E., Prieditis, G., Gryaznov, D., **Platonenko**, A., Kotomin, E. A., Popov, A. I., Atomic, electronic and magnetic structure of an oxygen interstitial in neutron-irradiated Al2O3 single crystals, Scientific Reports, **10** (2020): 15852. IF=4.58
- [P8] **Platonenko, A.,** Gryaznov, D. Popov, A. I., Dovesi, R., Kotomin, E. A., First principles calculations of the vibrational properties of single and dimer F-type centers in corundum crystals, Journal of Chemical Physics, **153** (2020): 134107. IF=2.99

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